







TPS7A20L SBVS447 - JANUARY 2024

TPS7A20L 300mA, Low-Noise, Low-I_Q, High-PSRR LDO Voltage Regulator With 1.2V Logic Compatible Enable

1 Features

Low output voltage noise: 7µV_{RMS} No noise-bypass capacitor required

High PSRR: 95dB at 1kHz

Very low I_O: 6.5µA

Input voltage range: 1.6V to 6.0V Output voltage range: 0.8V to 5.5V Output voltage tolerance: ±1.5% (max)

Very low dropout:

- 140mV (max) at 300mA (V_{OUT} = 3.3V)

Low inrush current

Smart enable pulldown

Stable with 1µF minimum ceramic output capacitor

Enable input compatible with 1.2V logic

Package: 1mm × 1mm X2SON

2 Applications

Smartphones and tablets

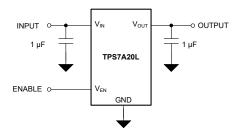
IP network cameras

Portable medical equipment

Smart meters and field transmitters

Motor drives

Wearables



Simplified Schematic

3 Description

The TPS7A20L is an ultra-small, low-dropout (LDO) linear regulator that can source 300mA of output current. The TPS7A20L is designed to provide low noise, high PSRR, and excellent load and line transient performance that can meet the requirements of RF and other sensitive analog circuits. Using innovative design techniques, the TPS7A20L offers an ultra-low noise performance without the addition of a noise bypass capacitor. The TPS7A20L also provides the advantage of low quiescent current, which can be beneficial for batterypowered applications. With an input voltage range of 1.6V to 6.0V and an output range of 0.8V to 5.5V, the TPS7A20L can be used for a wide variety of applications. The device uses a precision reference circuit to provide a maximum accuracy of 1.5% over load, line, and temperature variations.

The TPS7A20L features an internal soft-start to lower the inrush current, thus minimizing the input voltage drop during start up. The device is stable with small ceramic capacitors, allowing for a small overall solution size.

The TPS7A20L has a smart enable input circuit with an internally controlled pulldown resistor that keeps the LDO disabled even when the EN pin is left floating and helps eliminate the external components used to pulldown the EN pin. The enable input logic thresholds are compatible with the output levels of 1.2V logic devices.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾	
TPS7A20L	DQN (X2SON, 4)	1mm × 1mm	

- For more information, see the Mechanical, Packaging, and Orderable Information.
- The package size (length × width) is a nominal value and includes pins, where applicable.



Table of Contents

1 Features	1	7 Application and Implementation	23
2 Applications	1	7.1 Application Information	23
3 Description	1	7.2 Typical Application	26
4 Pin Configuration and Functions	3	7.3 Power Supply Recommendations	27
5 Specifications	4	7.4 Layout	27
5.1 Absolute Maximum Ratings		8 Device and Documentation Support	28
5.2 ESD Ratings		8.1 Device Support	28
5.3 Recommended Operating Conditions	4	8.2 Documentation Support	28
5.4 Thermal Information	5	8.3 Receiving Notification of Documentation Upda	tes28
5.5 Electrical Characteristics	5	8.4 Support Resources	28
5.6 Switching Characteristics	6	8.5 Trademarks	28
5.7 Typical Characteristics	7	8.6 Electrostatic Discharge Caution	28
6 Detailed Description		8.7 Glossary	28
6.1 Overview		9 Revision History	29
6.2 Functional Block Diagram	19	10 Mechanical, Packaging, and Orderable	
6.3 Feature Description	20	Information	29
6.4 Device Functional Modes			



4 Pin Configuration and Functions

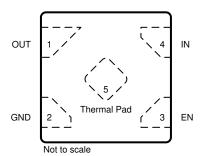


Figure 4-1. DQN Package, 4-Pin X2SON (Top View)

Pin Functions

PIN		TYPE(1)	DESCRIPTION
NAME	X2SON	ITPE	DESCRIPTION
EN	3	I	Enable input. A low voltage ($<$ V _{EN(LOW)}) on this pin turns the regulator off and discharges the output pin to GND. A high voltage ($>$ V _{EN(HI)}) on this pin enables the regulator output. This pin has an internal 500-k Ω pulldown resistor to hold the regulator off by default. When V _{EN} $>$ V _{EN(HI)} , the 500-k Ω pulldown is disconnected to reduce input current.
GND	2	G	Common ground.
IN	4	I	Input voltage supply. For best transient response and to minimize input impedance, use the nominal value or larger capacitor from IN to ground as listed in the <i>Recommended Operating Conditions</i> table. Place the input capacitor as close to the IN and GND pins of the device as possible.
OUT	1	0	Regulated output voltage. A low equivalent series resistance (ESR) capacitor is required from OUT to ground for stability. For best transient response, use the nominal recommended value or larger capacitor listed in the <i>Recommended Operating Conditions</i> table. Place the output capacitor as close to the OUT and GND pins of the device as possible. An internal 150- Ω (typical) pulldown resistor prevents a charge from remaining on V_{OUT} when the regulator is in shutdown mode (V_{EN} < $V_{EN(LOW)}$).
Thermal Pad	5	_	Thermal pad for the X2SON package. Connect this pad to GND or leave floating. Do not connect to any potential other than GND. Connect the thermal pad to a large-area ground plane for best thermal performance.

⁽¹⁾ I = Input, O = output, G = ground.



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1) (3)

		MIN	MAX	UNIT
	V _{IN}	-0.3	6.5	
Voltage	V _{OUT}	-0.3	6.5 or V _{IN} + 0.3 ⁽²⁾	V
	V _{EN}	-0.3	6.5	
Current	Maximum output ⁽⁴⁾	Internall	y limited	Α
Temperature	Operating junction, T _J	-40	150	°C
Temperature	Storage, T _{stg}	-65	150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- (2) The maximum value of V_{OUT} is the lesser of 6.5 V or $(V_{IN} + 0.3 \text{ V})$.
- (3) All voltages are with respect to the GND pin.
- (4) Internal thermal shutdown circuitry protects the device from permanent damage.

5.2 ESD Ratings

				VALUE	UNIT
	.,	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
"	(ESD)		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±750	v

- (1) JEDEC document JEP155 states that 500-V HBM allows safemanufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safemanufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	NOM MAX	UNIT
V _{IN}	Input supply voltage	1.6	6.0	V
V _{EN}	Enable input voltage	0	6.0	V
V _{OUT}	Nominal output voltage range	0.8	5.5	V
I _{OUT}	Output current	0	300	mA
C _{IN}	Input capacitor ⁽²⁾		1	μF
C _{OUT}	Output capacitor ⁽³⁾	1	200	μF
ESR	Output capacitor effective series resistance		100	mΩ
T _J	Operating junction temperature	-40	125	°C

- (1) All voltages are with respect to GND.
- (2) An input capacitor is not required for LDO stability. However, an input capacitor with an effective value of 0.47 μF minimum is recommended to counteract the effect of source resistance and inductance, which may in some cases cause symptoms of system-level instability such as ringing or oscillation, especially in the presence of load transients.
- (3) Effective output capacitance of 0.47 µF minimum and 200 µF maximum is required for stability.

Product Folder Links: TPS7A20L



5.4 Thermal Information

		TPS7A20L	
THERMAL METRIC ⁽¹⁾		DQN (X2SON)	UNIT
		4 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	166.1	°C/W
R ₀ JC(top)	Junction-to-case (top) thermal resistance	103.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	110.6	°C/W
ΨЈТ	Junction-to-top characterization parameter	3.0	°C/W
ΨЈВ	Junction-to-board characterization parameter	103.3	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	98.8	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.5 Electrical Characteristics

at operating temperature range (T $_J$ = -40° C to +125 $^{\circ}$ C), V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6V, whichever is greater, V_{EN} = 1.0 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F (unless otherwise noted); all typical values are at T_J = 25 $^{\circ}$ C

	PARAMETER	TEST CO	ONDITIONS	MIN	TYP	MAX	UNIT
ΔV _{OUT}	Output voltage tolerance	$V_{IN} = (V_{OUT(NOM)} + 0.3 \text{ V}) \text{ to}$ $I_{OUT} = 1 \text{ mA to } 300 \text{ mA},$ $V_{OUT} \ge 1.85 \text{ V}$				1.5	%
ΔV _{OUT}	Output voltage tolerance	$V_{IN} = (V_{OUT(NOM)} + 0.5 \text{ V}) \text{ to}$ $I_{OUT} = 1 \text{ mA to } 300 \text{ mA}$ $V_{OUT} < 1.85 \text{ V}$	o 6.0 V,	-30		30	mV
ΔV _{OUT}	Line regulation	$V_{IN} = (V_{OUT(NOM)} + 0.3 \text{ V}) \text{ to}$ $I_{OUT} = 1 \text{ mA}$	o 6.0 V,		0.03		%/V
ΔV_{OUT}	Load regulation	I _{OUT} = 1 mA to 300 mA			13		mV
			T _J = 25°C		6.5	8.5	
la	Quiescent ground current	$V_{EN} = V_{IN} = 6 V,$ $I_{OUT} = 0 \text{ mA}$	$T_J = -40$ °C to 85°C			10	μA
I _{GND}	Quiescent ground current	1001 2 1111	$T_J = -40^{\circ}\text{C to } 125^{\circ}\text{C}$			15	μА
		V _{EN} = V _{IN} = 6 V, I _{OUT} = 300	mA		2000		
I _{SHDN}	Shutdown ground current	V _{EN} = 0 V (disabled), V _{IN} =	6.0 V, T _J = 25°C		0.07	0.2	μA
I _{GND(DO)}	I _{GND} in dropout	V _{IN} ≤ V _{OUT(NOM)} , I _{OUT} = 0	mA, V _{EN} = V _{IN}		6.5	15	μA
	Dropout voltage	I _{OUT} = 300 mA, V _{OUT} = 95% x V _{OUT(NOM)} ,	$0.8 \text{ V} \le V_{OUT} < 1.0 \text{ V}^{(1)}$			690	
			$1.0 \text{ V} \le V_{\text{OUT}} < 1.2 \text{ V}^{(1)}$			490	mV
V_{DO}			$1.2 \text{ V} \le V_{\text{OUT}} < 1.5 \text{ V}^{(1)}$			355	
			1.5 V ≤ V _{OUT} < 2.5 V			200	
			2.5 V ≤ V _{OUT} < 5.5 V			140	
I	Output current limit	$V_{OUT} = 0.9 \times V_{OUT(NOM)},$ $V_{IN} = V_{OUT(NOM)} + 0.5 V$	V _{OUT} < 1.5 V	360	520	730	mA
I _{CL}		$V_{OUT} = 0.9 \times V_{OUT(NOM)},$ $V_{IN} = V_{OUT(NOM)} + 0.3 \text{ V}$	V _{OUT} ≥ 1.5 V	360	520	730	IIIA
I _{SC}	Short-circuit current limit	V _{OUT} = 0 V			160		mA
			f = 100 Hz		95		
			f = 1 kHz		95		
		I _{OUT} = 20 mA, V _{IN} = V _{OUT} + 1.0 V	f = 10 kHz		75		
		1114 1001 112	f = 100 kHz		75		
PSRR	Dower aupply rejection ratio		f = 1 MHz		45		I.D.
r ork	Power-supply rejection ratio		f = 100 Hz		65		dB
			f = 1 kHz		92		-
		$I_{OUT} = 300 \text{ mA},$ $V_{IN} = V_{OUT} + 1.0 \text{ V}$	f = 10 kHz		75		
		VIII VOUT - 1.5 V	f = 100 kHz		60		
			f = 1 MHz		40		1

Copyright © 2024 Texas Instruments Incorporated

Submit Document Feedback



5.5 Electrical Characteristics (continued)

at operating temperature range (T_J = -40° C to +125°C), V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6V, whichever is greater, V_{EN} = 1.0 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F (unless otherwise noted); all typical values are at T_J = 25°C

PARAMETER		TEST C	TEST CONDITIONS		TYP	MAX	UNIT
\/		BW = 10 Hz to 100 kHz,	I _{OUT} = 300 mA		7		.,
V_N	Output noise voltage	V _{OUT} = 2.8 V	I _{OUT} = 1 mA		10		μV_{RMS}
R _{PULLDOWN}	Output automatic discharge pulldown resistance	V _{EN} < V _{EN(LOW)} (output dis	abled), V _{IN} = 3.1 V		150		Ω
-	Thermal shutdown	T _J rising			165		°C
T _{SD}	Thermal shuldown	T _J falling			140		-0
V _{EN(LOW)}	Low input threshold	V _{IN} = 1.6 V to 6.0 V, V _{EN} falling until the output is disabled				0.43	V
V _{EN(HI)}	High input threshold	V _{IN} = 1.6 V to 6.0 V V _{EN} rising until the output is	V _{IN} = 1.6 V to 6.0 V V _{EN} rising until the output is enabled				V
	UVLO threshold	V _{IN} rising		1.17	1.35	1.59	V
V_{UVLO}	OVLO threshold	V _{IN} falling		1.11	1.3	1.55	V
V _{UVLO(HYST)}	UVLO hysteresis				50		mV
I _{EN}	EN input leakage current	V _{EN} = 6.0 V and V _{IN} = 6.0 V			90	250	nA
R _{EN(PULL} -	Smart enable pulldown resistor	V _{EN} = 0.25 V			500		ΚΩ

⁽¹⁾ Design simulation data only

5.6 Switching Characteristics

at operating temperature range (T_J = -40° C to +125 $^{\circ}$ C), V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6V, whichever is greater, V_{EN} = 1.0 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F (unless otherwise noted); all typical values are at T_J = 25 $^{\circ}$ C

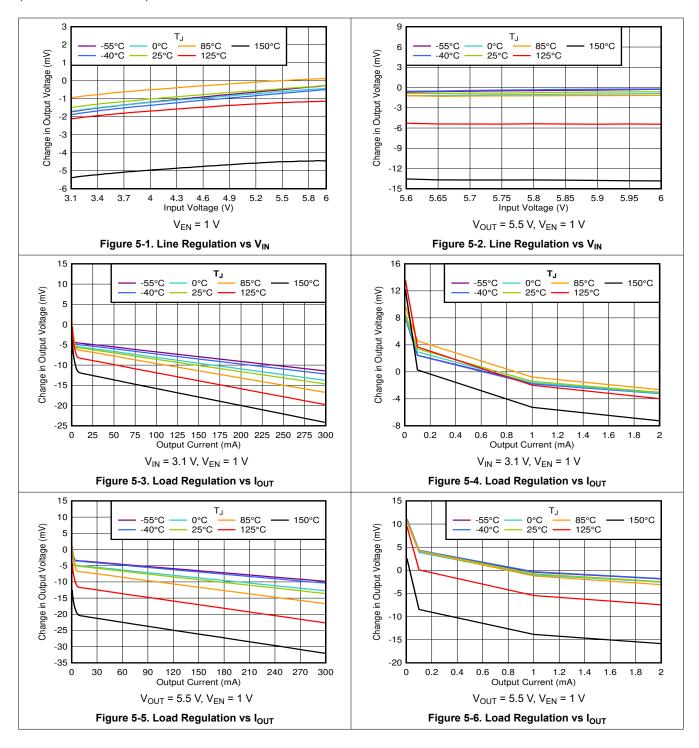
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t _{STR}	Start-up time	From $V_{EN} > V_{EN(HI)}$ to $V_{OUT} = 95\%$ of $V_{OUT(NOM)}$		750	1150	μs

Product Folder Links: TPS7A20L



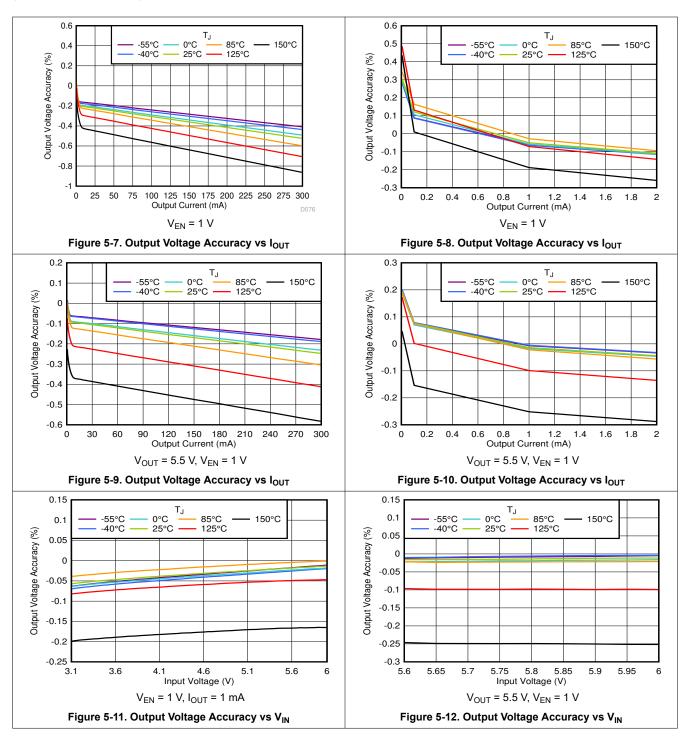
5.7 Typical Characteristics

 $V_{IN} = V_{OUT(NOM)} + 0.3 \text{ V}$ or 1.6 V (whichever is greater), $V_{OUT} = 2.8 \text{ V}$, $I_{OUT} = 1 \text{ mA}$, $C_{IN} = 1 \text{ }\mu\text{F}$, $C_{OUT} = 1 \text{ }\mu\text{F}$, and $T_A = 25 ^{\circ}\text{C}$ (unless otherwise noted)





 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)

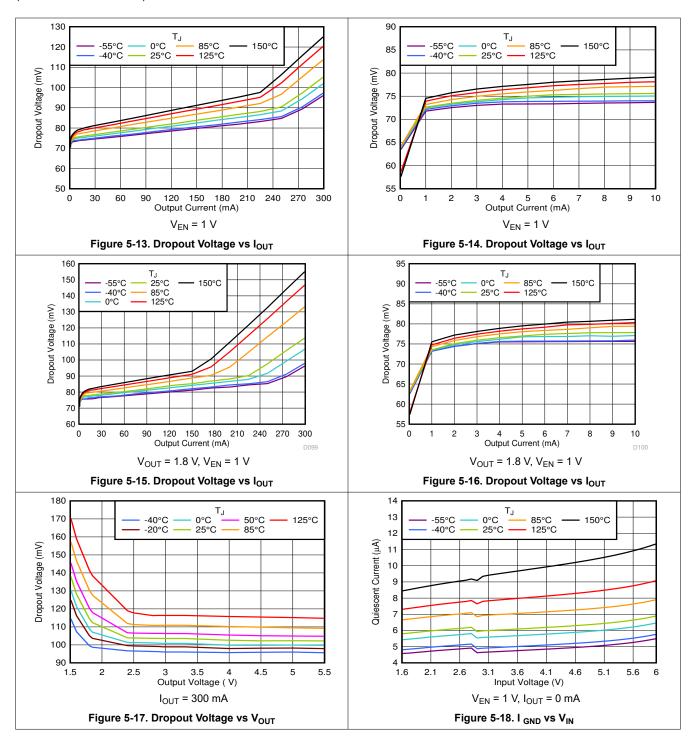


Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated

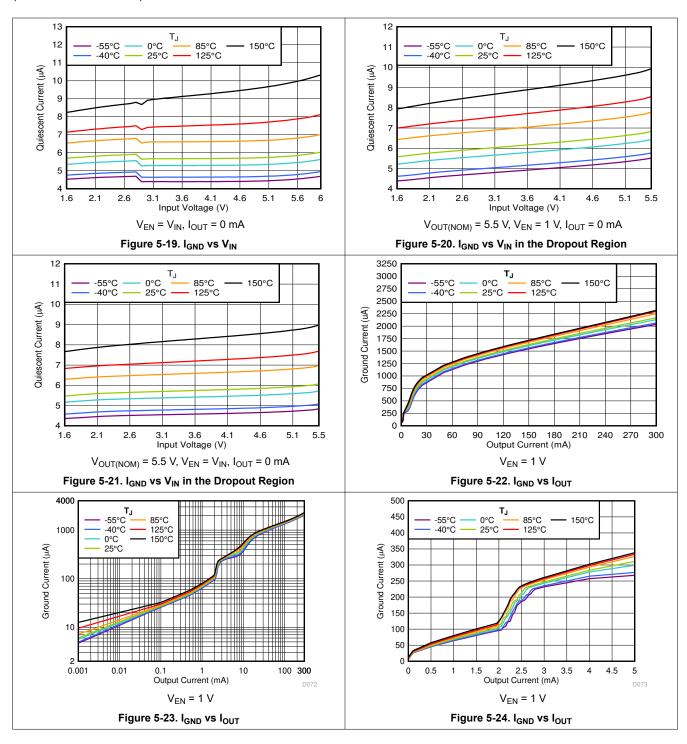


 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)





 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)

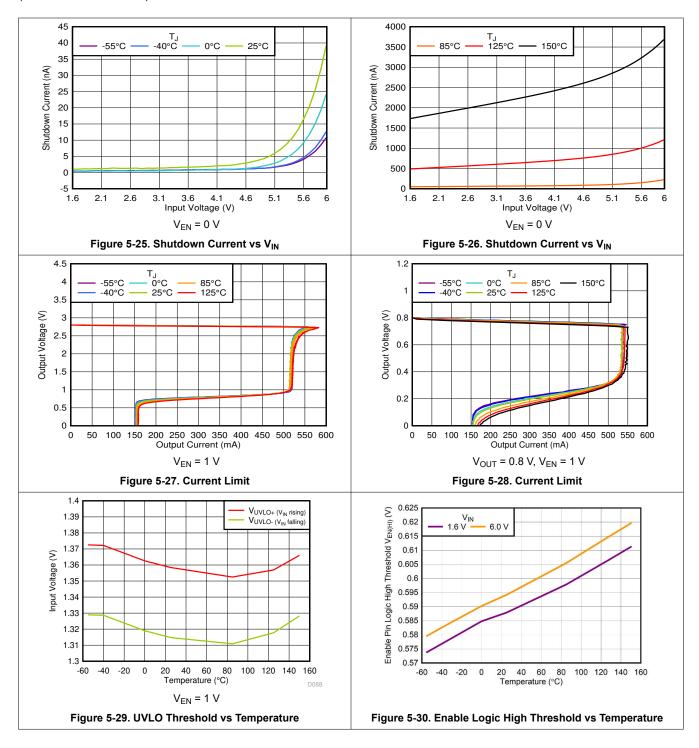


Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated



 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)

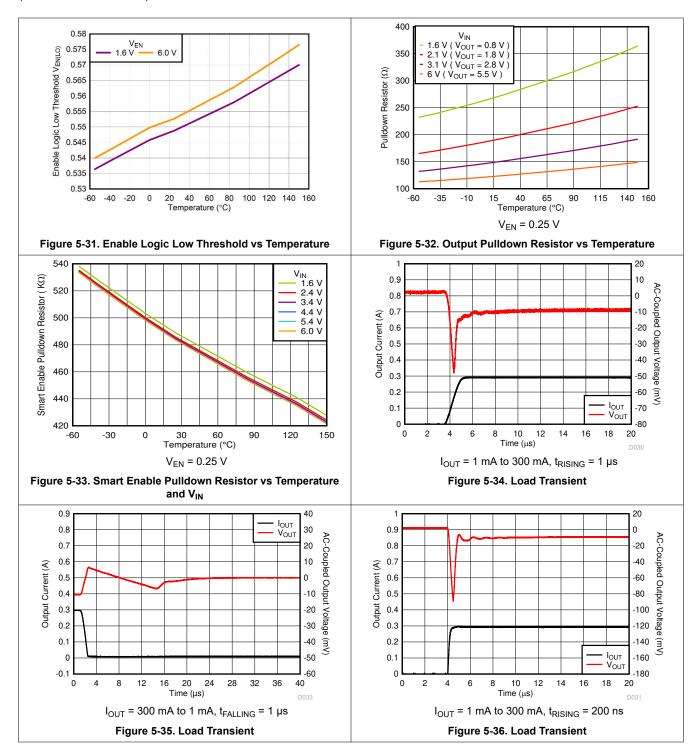


Copyright © 2024 Texas Instruments Incorporated

Submit Document Feedback



 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)

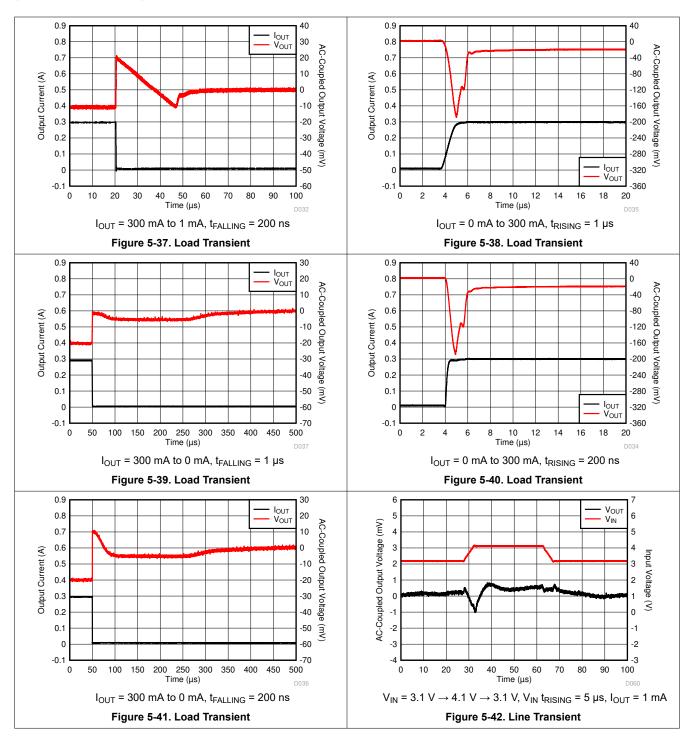


Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated

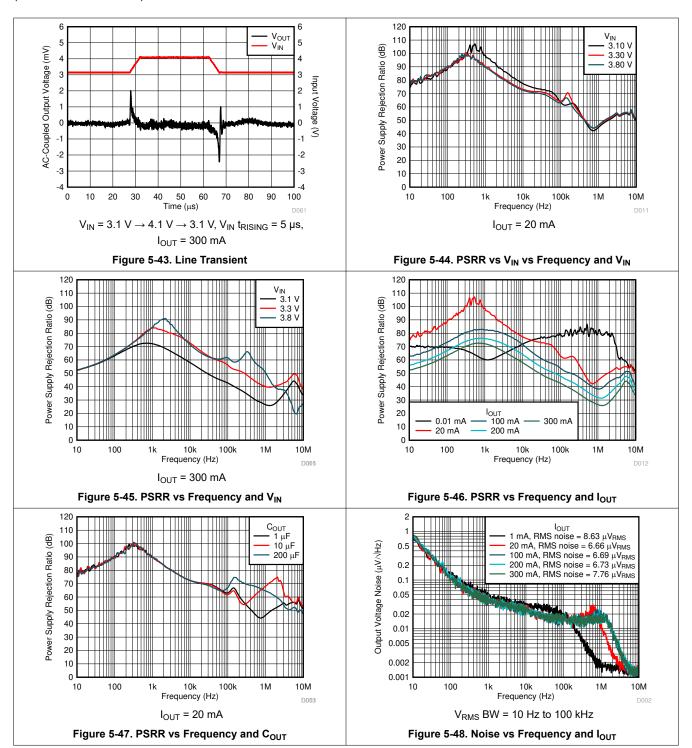


 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)





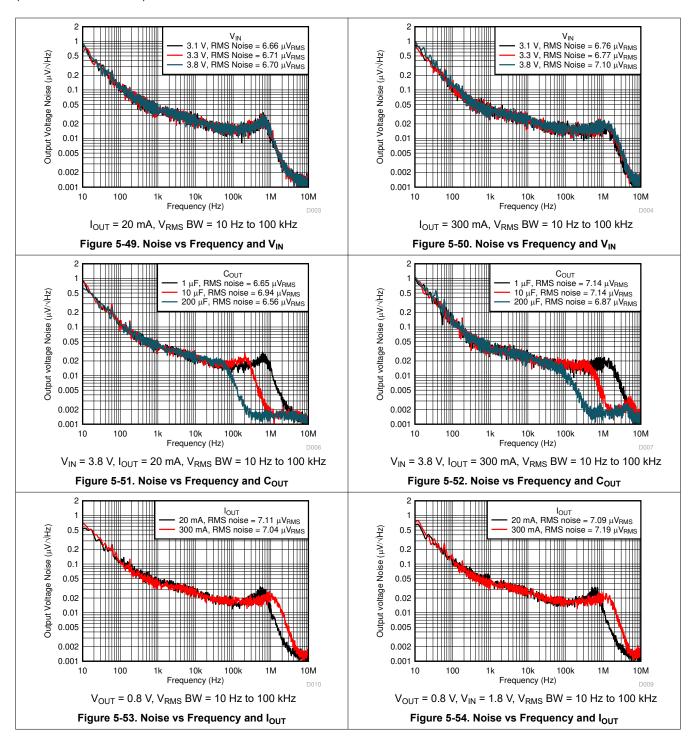
 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)



Submit Document Feedback

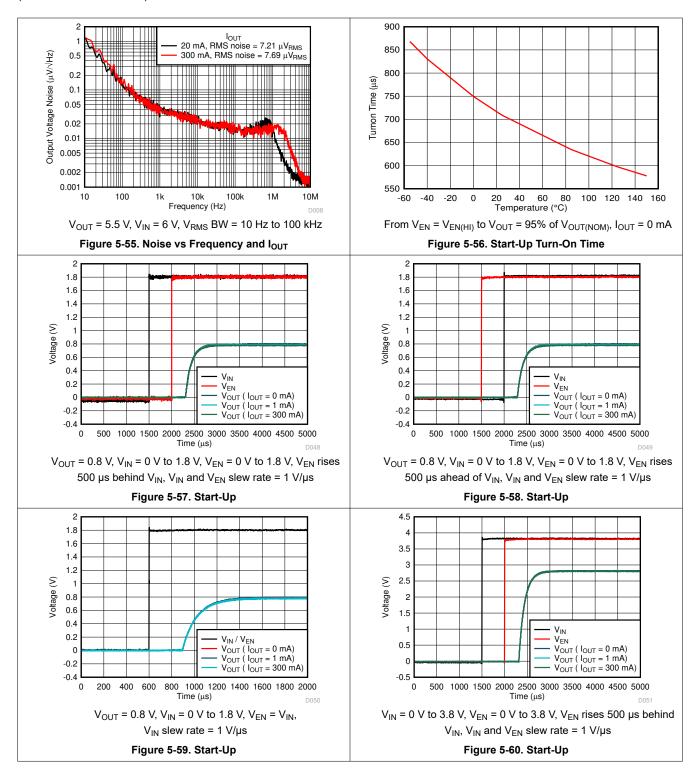
Copyright © 2024 Texas Instruments Incorporated

 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)





 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)

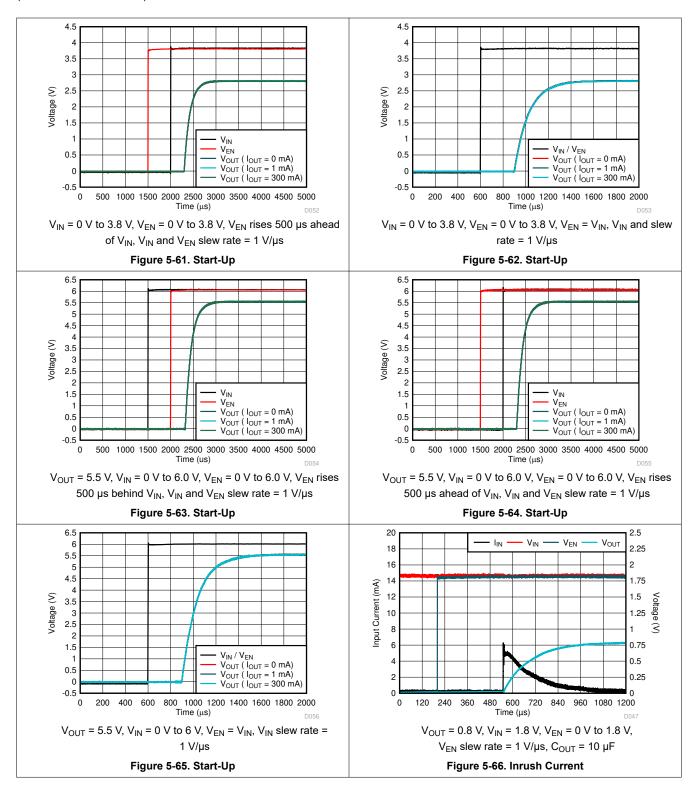


Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated

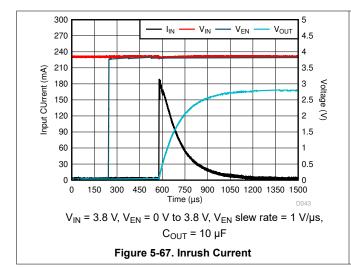


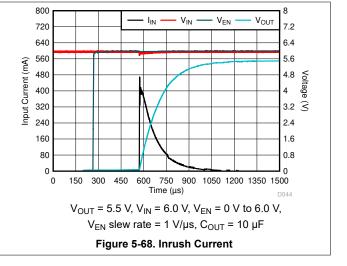
 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)





 V_{IN} = $V_{OUT(NOM)}$ + 0.3 V or 1.6 V (whichever is greater), V_{OUT} = 2.8 V, I_{OUT} = 1 mA, C_{IN} = 1 μ F, C_{OUT} = 1 μ F, and T_A = 25°C (unless otherwise noted)





Submit Document Feedback

Copyright © 2024 Texas Instruments Incorporated



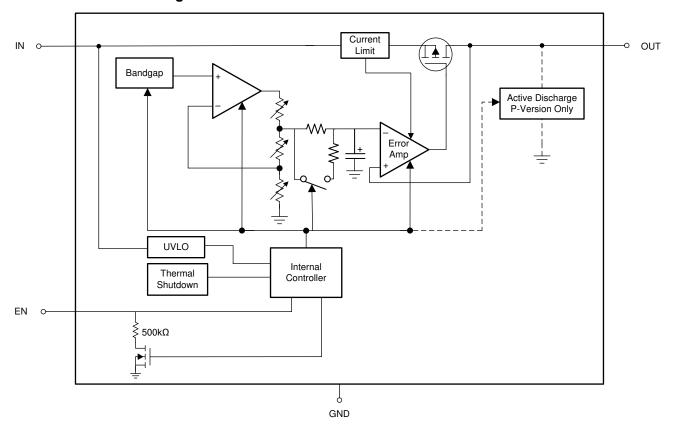
6 Detailed Description

6.1 Overview

Designed to meet the needs of sensitive RF and analog circuits, the TPS7A20L provides low noise, high PSRR, low quiescent current, and low line and load transient response figures. Using innovative design techniques, the TPS7A20L offers class-leading noise performance without the need for a separate noise filter capacitor.

The TPS7A20L is designed to operate with a single $1-\mu F$ input capacitor and a single $1-\mu F$ ceramic output capacitor.

6.2 Functional Block Diagram



6.3 Feature Description

6.3.1 Low Output Noise

Any internal noise at the TPS7A20L reference voltage is reduced by a first-order, low-pass RC filter before being passed to the output buffer stage. The low-pass RC filter has a -3-dB cutoff frequency of approximately 0.1 Hz.

During start-up, the filter resistor is bypassed to reduce output rise time; the filter begins normal operation after the output voltage reaches the correct value.

6.3.2 Smart Enable

The enable (EN) input polarity is active high. The output voltage is enabled when the voltage of the enable input is greater than V_{FN(HI)} and disabled when the enable input voltage is less than V_{FN(I OW)}. If independent control of the output voltage is not needed, connect EN to IN.

This device has a smart enable circuit to reduce guiescent current. When the voltage on the enable pin is driven above V_{EN(HI)}, as listed in the *Electrical Characteristics* table, the device is enabled and the smart enable internal pulldown resistor (R_{EN(PULLDOWN)}) is disconnected. When the enable pin is floating, the R_{EN(PULLDOWN)} is connected and pulls the enable pin low to disable the device. The R_{FN(PULLDOWN)} value is listed in the Electrical Characteristics table.

6.3.3 Dropout Voltage

Dropout voltage (V_{DO}) is defined as the input voltage minus the output voltage $(V_{IN} - V_{OUT})$ at the rated output current (I_{RATED}), where the pass transistor is fully on. I_{RATED} is the maximum I_{OUT} listed in the Recommended Operating Conditions table. The pass transistor is in the ohmic or triode region of operation, and acts as a switch. The dropout voltage indirectly specifies a minimum input voltage greater than the nominal programmed output voltage at which the output voltage is expected to stay in regulation. If the input voltage falls to less than the value required to maintain output regulation, then the output voltage falls as well.

For a CMOS regulator, the dropout voltage is determined by the drain-source on-state resistance (R_{DS(ON)}) of the pass transistor. Therefore, if the linear regulator operates at less than the rated current, the dropout voltage for that current scales accordingly. The following equation calculates the R_{DS(ON)} of the device.

$$R_{\rm DS(ON)} = \frac{V_{\rm DO}}{I_{\rm RATED}} \tag{1}$$

6.3.4 Foldback Current Limit

The device has an internal current limit circuit that protects the regulator during transient high-load current faults or shorting events. The current limit is a hybrid brick-wall-foldback scheme. The current limit transitions from a brick-wall scheme to a foldback scheme at the foldback voltage (VFOLDBACK). In a high-load current fault with the output voltage above V_{FOLDBACK}, the brick-wall scheme limits the output current to the current limit (I_{CL}). When the voltage drops below V_{FOLDBACK}, a foldback current limit activates that scales back the current as the output voltage approaches GND. When the output is shorted, the device supplies a typical current called the short-circuit current limit (I_{SC}). I_{CL} and I_{SC} are listed in the *Electrical Characteristics* table.

The output voltage is not regulated when the device is in current limit. When a current limit event occurs, the device begins to heat up because of the increase in power dissipation. When the device is in brick-wall current limit, the pass transistor dissipates power [$(V_{IN} - V_{OUT}) \times I_{CL}$]. When the device output is shorted and the output is below $V_{FOLDBACK}$, the pass transistor dissipates power [$(V_{IN} - V_{OUT}) \times I_{SC}$]. If thermal shutdown is triggered, the device turns off. After the device cools down, the internal thermal shutdown circuit turns the device back on. If the output current fault condition continues, the device cycles between current limit and thermal shutdown. For more information on current limits, see the *Know Your Limits* application note.

Product Folder Links: TPS7A20L

Figure 6-1 shows a diagram of the foldback current limit.

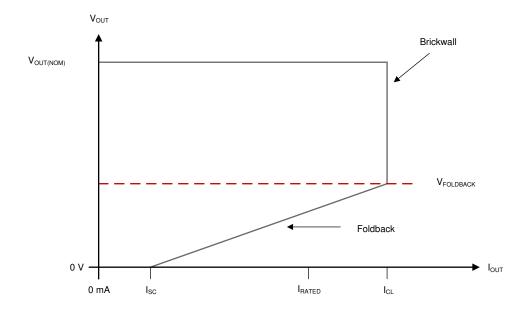


Figure 6-1. Foldback Current Limit

6.3.5 Undervoltage Lockout (UVLO)

The device has an independent undervoltage lockout (UVLO) circuit that monitors the input voltage, allowing a controlled and consistent turn on and off of the output voltage. To prevent the device from turning off if the input drops during turn on, the UVLO has hysteresis as specified in the *Electrical Characteristics* table.

6.3.6 Thermal Shutdown

A thermal shutdown protection circuit disables the LDO when the junction temperature (T_J) of the pass transistor rises to $T_{SD(shutdown)}$ (typical). Thermal shutdown hysteresis makes sure that the device resets (turns on) when the temperature falls to $T_{SD(reset)}$ (typical).

The thermal time-constant of the semiconductor die is fairly short, thus the device can cycle on and off when thermal shutdown is reached until power dissipation is reduced. Power dissipation during start-up can be high from large $V_{\text{IN}} - V_{\text{OUT}}$ voltage drops across the device or from high inrush currents charging large output capacitors. Under some conditions, the thermal shutdown protection disables the device before start-up completes.

For reliable operation, limit the junction temperature to the maximum listed in the *Recommended Operating Conditions* table. Operation above this maximum temperature causes the device to exceed operational specifications. Although the internal protection circuitry of the device is designed to protect against thermal overload conditions, this circuitry is not intended to replace proper heat sinking. Continuously running the device into thermal shutdown or above the maximum recommended junction temperature reduces long-term reliability.

6.3.7 Active Discharge

An internal pulldown MOSFET connects a resistor from OUT to ground when the device is disabled to actively discharge the output capacitance. The active discharge circuit is activated by driving EN low or by the voltage on IN falling below the undervoltage lockout (UVLO) threshold.

Do not rely on the active discharge circuit for discharging a large amount of output capacitance after the input supply has collapsed because reverse current can possibly flow from the output to the input. This reverse current flow can cause damage to the device. Limit reverse current to no more than 5% of the device rated current for a short period of time.

6.4 Device Functional Modes

6.4.1 Device Functional Mode Comparison

Table 6-1 shows the conditions that lead to the different modes of operation. See the *Electrical Characteristics* table for parameter values.

	Table 6-1. Bevice i diretional mode companison						
OPERATING MODE	PARAMETER						
OPERATING WIDDE	V _{IN}	V _{EN}	I _{OUT}	TJ			
Normal operation	$V_{IN} > V_{OUT(nom)} + V_{DO}$ and $V_{IN} > V_{IN(min)}$	V _{EN} > V _{EN(HI)}	I _{OUT} < I _{OUT(max)}	$T_J < T_{SD(shutdown)}$			
Dropout operation	$V_{IN(min)} < V_{IN} < V_{OUT(nom)} + V_{DO}$	V _{EN} > V _{EN(HI)}	I _{OUT} < I _{OUT(max)}	$T_J < T_{SD(shutdown)}$			
Disabled (any true condition disables the device)	V _{IN} < V _{UVLO}	V _{EN} < V _{EN(LOW)}	Not applicable	$T_{J} > T_{SD(shutdown)}$			

Table 6-1. Device Functional Mode Comparison

6.4.2 Normal Operation

The device regulates to the nominal output voltage when the following conditions are met:

- The input voltage is greater than the nominal output voltage plus the dropout voltage (V_{OUT(nom)} + V_{DO})
- The output current is less than the current limit (I_{OUT} < I_{CL})
- The device junction temperature is less than the thermal shutdown temperature (T_J < T_{SD})
- The enable voltage has previously exceeded the enable rising threshold voltage and has not yet decreased to less than the enable falling threshold

6.4.3 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this mode, the output voltage tracks the input voltage. During this mode, the transient performance of the device becomes significantly degraded because the pass transistor is in the ohmic or triode region, and acts as a switch. Line or load transients in dropout can result in large output voltage deviations.

When the device is in a steady dropout state (defined as when the device is in dropout, $V_{IN} < V_{OUT(NOM)} + V_{DO}$, directly after being in a normal regulation state, but *not* during start-up), the pass transistor is driven into the ohmic or triode region. When the input voltage returns to a value greater than or equal to the nominal output voltage plus the dropout voltage ($V_{OUT(NOM)} + V_{DO}$), the output voltage can overshoot for a short period of time while the device pulls the pass transistor back into the linear region.

6.4.4 Disabled

The output of the LDO can be shut down by driving EN to less than $V_{\text{EN(LOW)}}$ (see the *Electrical Characteristics* table). When disabled, the pass transistor is turned off, internal circuits are shut down, and the output voltage is actively discharged to ground by an internal discharge circuit between OUT and ground.

Product Folder Links: TPS7A20L

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

7.1.1 Recommended Capacitor Types

The device is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input and output. Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but must be used with good judgment. Ceramic capacitors that employ X7R-, X5R-, and C0G-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, the effective capacitance varies with operating voltage and temperature. Generally, expect the effective capacitance to decrease by as much as 50%. The input and output capacitors recommended in the *Recommended Operating Conditions* table account for an effective capacitance of approximately 50% of the nominal value.

7.1.2 Input and Output Capacitor Requirements

Although the LDO is stable without an input capacitor, good analog design practice is to connect a capacitor from IN to GND, with a value at least equal to the nominal value specified in the *Recommended Operating Conditions* table. The input capacitor counteracts reactive input sources and improves transient response, input ripple, and PSRR, and is recommended if the source impedance is greater than $0.5~\Omega$. When the source resistance and inductance are sufficiently high, especially in the presence of load transients, the overall system can be susceptible to instability (including ringing and sustained oscillation) and other performance degradation if there is insufficient capacitance between IN and GND. A capacitor with a value greater than the minimum can be necessary if large, fast-rise-time load or line transients are anticipated or if the device is located more than a few centimeters from the input power source.

An output capacitor of an appropriate value helps provide stability and improve dynamic performance. Use an output capacitor within the range specified in the *Recommended Operating Conditions* table.

7.1.3 Load Transient Response

The load-step transient response is the output voltage response by the LDO to a step in load current, whereby output voltage regulation is maintained. There are two key transitions during a load transient response: the transition from a light to a heavy load and the transition from a heavy to a light load. The regions shown in Figure 7-1 are broken down as follows. Regions A, E, and H are where the output voltage is in steady state.

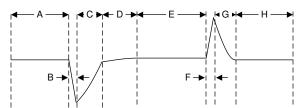


Figure 7-1. Load Transient Waveform

During transitions from a light load to a heavy load, the:

• Initial voltage dip is a result of the depletion of the output capacitor charge and parasitic impedance to the output capacitor (region B)



Recovery from the dip results from the LDO increasing the sourcing current, and leads to output voltage regulation (region C)

During transitions from a heavy load to a light load, the:

- Initial voltage rise results from the LDO sourcing a large current, and leads to the output capacitor charge to increase (region F)
- Recovery from the rise results from the LDO decreasing the sourcing current in combination with the load discharging the output capacitor (region G)

A larger output capacitance reduces the peaks during a load transient but slows down the response time of the device. A larger DC load also reduces the peaks because the amplitude of the transition is lowered and a higher current discharge path is provided for the output capacitor.

7.1.4 Undervoltage Lockout (UVLO) Operation

The UVLO circuit makes sure that the device stays disabled before the input supply reaches the minimum operational voltage range, and makes sure that the device shuts down when the input supply collapses. Figure 7-2 shows the UVLO circuit response to various input voltage events. The diagram can be separated into the following parts:

- Region A: The device does not start until the input reaches the UVLO rising threshold.
- Region B: Normal operation, regulating device.
- Region C: Brownout event above the UVLO falling threshold (UVLO rising threshold UVLO hysteresis). The output can fall out of regulation but the device remains enabled.
- Region D: Normal operation, regulating device.
- Region E: Brownout event below the UVLO falling threshold. The device is disabled in most cases and the output falls because of the load and active discharge circuit. The device is re-enabled when the UVLO rising threshold is reached by the input voltage and a normal start-up follows.
- Region F: Normal operation followed by the input falling to the UVLO falling threshold.
- Region G: The device is disabled when the input voltage falls below the UVLO falling threshold to 0 V. The output falls because of the load and active discharge circuit.

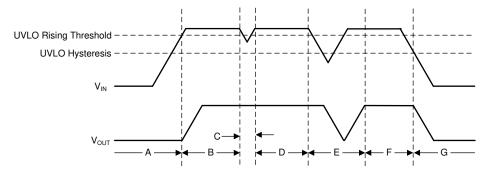


Figure 7-2. Typical UVLO Operation

7.1.5 Power Dissipation (P_D)

Circuit reliability demands that proper consideration be given to device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must be as free as possible of other heat-generating devices that cause added thermal stresses.

As a first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. Use Equation 2 to approximate P_D:

$$P_{D} = (V_{IN} - V_{OUT}) \times I_{OUT}$$
 (2)

Product Folder Links: TPS7A20L



Power dissipation can be minimized, and thus greater efficiency achieved, by proper selection of the system voltage rails. Proper selection allows the minimum input-to-output voltage differential to be obtained. The low dropout of the TPS7A20 allows for maximum efficiency across a wide range of output voltages.

The main heat conduction path for the device is through the thermal pad on the package. As such, the thermal pad must be soldered to a copper pad area under the device. This pad area contains an array of plated vias that conduct heat to any inner plane areas or to a bottom-side copper plane.

The maximum power dissipation determines the maximum allowable junction temperature (T_J) for the device. According to Equation 3, power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance $(R_{\theta JA})$ of the combined PCB and device package and the temperature of the ambient air (T_A) . Equation 4 rearranges Equation 3 for output current.

$$T_{J} = T_{A} + (R_{\theta JA} \times P_{D}) \tag{3}$$

$$I_{OUT} = (T_J - T_A) / [R_{\theta JA} \times (V_{IN} - V_{OUT})]$$
(4)

Unfortunately, this thermal resistance ($R_{\theta JA}$) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The $R_{\theta JA}$ recorded in the *Thermal Information* table is determined by the JEDEC standard, PCB, and copper-spreading area, and is only used as a relative measure of package thermal performance. For a well-designed thermal layout, $R_{\theta JA}$ is actually the sum of the X2SON package junction-to-case (bottom) thermal resistance ($R_{\theta JC(bot)}$) plus the thermal resistance contribution by the PCB copper.

7.1.5.1 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi (Ψ) thermal metrics to estimate the junction temperatures of the LDO when in-circuit on a typical PCB board application. These metrics are not strictly speaking thermal resistances, but rather offer practical and relative means of estimating junction temperatures. These psi metrics are determined to be significantly independent of the copper-spreading area. The key thermal metrics $(\Psi_{JT}$ and $\Psi_{JB})$ are used in accordance with Equation 5 and are given in the *Thermal Information* table.

$$\Psi_{JT}: T_J = T_T + \Psi_{JT} \times P_D \text{ and } \Psi_{JB}: T_J = T_B + \Psi_{JB} \times P_D$$
 (5)

where:

- P_D is the power dissipated as explained in Equation 2
- T_T is the temperature at the center-top of the device package
- T_B is the PCB surface temperature measured 1 mm from the device package and centered on the package edge

7.1.5.2 Recommended Area for Continuous Operation

The operational area of an LDO is limited by the dropout voltage, output current, junction temperature, and input voltage. The recommended area for continuous operation for a linear regulator is given in Figure 7-3 and can be separated into the following parts:

- Dropout voltage limits the minimum differential voltage between the input and the output (V_{IN} V_{OUT}) at a
 given output current level. See the *Dropout Operation* section for more details.
- The rated output currents limits the maximum recommended output current level. Exceeding this rating causes the device to fall out of specification.
- The rated junction temperature limits the maximum junction temperature of the device. Exceeding this rating
 causes the device to fall out of specification and reduces long-term reliability.
 - The shape of the slope is given by Equation 4. The slope is nonlinear because the maximum-rated junction temperature of the LDO is controlled by the power dissipation across the LDO; thus when V_{IN} V_{OUT} increases the output current must decrease.
- The rated input voltage range governs both the minimum and maximum of $V_{IN} V_{OUT}$.

Figure 7-3 shows the recommended area of operation for this device on a JEDEC-standard high-K board with a $R_{\theta,JA}$ as given in the *Thermal Information* table.

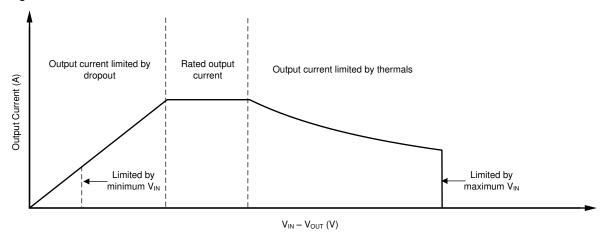


Figure 7-3. Region Description of Continuous Operation Regime

7.2 Typical Application

Figure 7-4 shows the typical application circuit for the TPS7A20. If needed, increase the input and output capacitances above the 1-µF minimum.

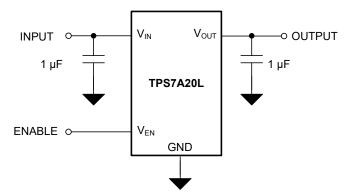


Figure 7-4. TPS7A20L Typical Application

7.2.1 Design Requirements

Table 7-1 summarizes the design requirements for Figure 7-4.

Table 7-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	3.1 V to 3.6 V
Output voltage	2.8 V
Output current	200 mA
Maximum ambient temperature	85°C

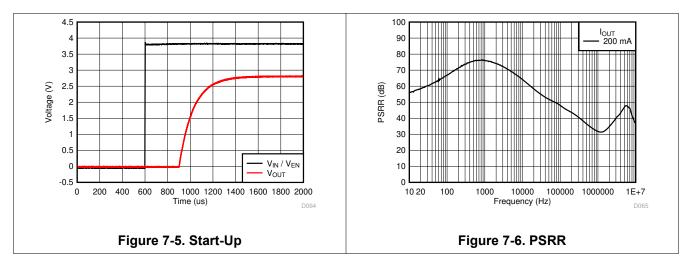
7.2.2 Detailed Design Procedure

For this design example, the 2.8-V output version (TPS7A20L28) is selected. A nominal 3.3-V input supply is assumed. Use a minimum 1.0-µF input capacitor to minimize the effect of resistance and inductance between the 3.3-V source and the LDO input. Use a minimum 1.0-µF output capacitor for stability and good load transient response. The dropout voltage (VDO) is less than 140 mV maximum at a 2.8-V output voltage and 300-mA

Product Folder Links: TPS7A20L

output current, so there are no dropout issues with a minimum input voltage of 3.0 V and a maximum output current of 200 mA.

7.2.3 Application Curves



7.3 Power Supply Recommendations

This device is designed to operate from an input supply voltage range of 1.6 V to 6.0 V. The input supply must be well regulated and free of spurious noise. To make sure that the output voltage is well regulated and dynamic performance is optimum, the input supply must be at least $V_{OUT(nom)} + 0.3 \text{ V}$ or 1.6 V, whichever is greater. Use a 1- μ F or greater input capacitor to reduce the impedance of the input supply, especially during transients.

7.4 Layout

7.4.1 Layout Guidelines

- Place input and output capacitors as close to the device as possible.
- Use copper planes for device connections to optimize thermal performance.
- Place thermal vias around the device to distribute the heat.
- Do not place a thermal via directly beneath the thermal pad of the DQN package. A via can wick solder or solder paste away from the thermal pad joint during the soldering process, leading to a compromised solder joint on the thermal pad.

7.4.2 Layout Example

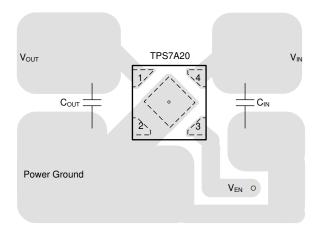


Figure 7-7. DQN Package (X2SON) Typical Layout



8 Device and Documentation Support

8.1 Device Support

8.1.1 Device Nomenclature

Table 8-1. Device Nomenclature

PRODUCT (1) (2)	V _{OUT}
TPS7A20Lxx(x)Pyyyz	 xx(x) is the nominal output voltage. For output voltages with a resolution of 100 mV, two digits are used in the ordering number; otherwise, three digits are used (for example, 28 = 2.8 V; 125 = 1.25 V). P indicates an active output discharge feature. All members of the TPS7A20L family actively discharge the output when the device is disabled. yyy is the package designator. z is the package quantity. R is for reel (3000 pieces for DQN).

⁽¹⁾ For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder on www.ti.com.

8.2 Documentation Support

8.2.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, Universal Low-Dropout (LDO) Linear Voltage Regulator MultiPkgLDOEVM-823 Evaluation Module user guide
- Texas Instruments, Semiconductor and IC Package Thermal Metrics application note

8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.4 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.5 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

8.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.7 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

Product Folder Links: TPS7A20L

⁽²⁾ Output voltages from 0.8 V to 5.5 V in 25-mV increments are available. Contact the factory for details and availability.



9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES				
January 2024	*	Initial Release				

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 9-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
TPS7A20L10PDQNR	Active	Production	X2SON (DQN) 4	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OU
TPS7A20L10PDQNR.A	Active	Production	X2SON (DQN) 4	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OU
TPS7A20L12PDQNR	Active	Production	X2SON (DQN) 4	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OV
TPS7A20L12PDQNR.A	Active	Production	X2SON (DQN) 4	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OV
TPS7A20L18PDQNR	Active	Production	X2SON (DQN) 4	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OW
TPS7A20L18PDQNR.A	Active	Production	X2SON (DQN) 4	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OW
TPS7A20L28PDQNR	Active	Production	X2SON (DQN) 4	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OX
TPS7A20L28PDQNR.A	Active	Production	X2SON (DQN) 4	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OX
TPS7A20L33PDQNR	Active	Production	X2SON (DQN) 4	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OZ
TPS7A20L33PDQNR.A	Active	Production	X2SON (DQN) 4	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	OZ

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

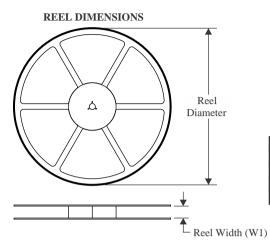
www.ti.com 9-Nov-2025

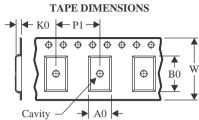
and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

www.ti.com 30-Apr-2024

TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

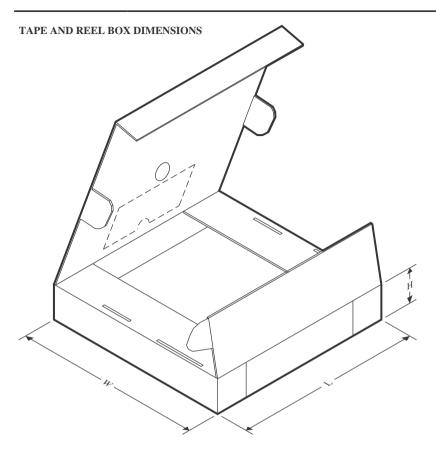


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS7A20L10PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A20L12PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A20L18PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A20L28PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2
TPS7A20L33PDQNR	X2SON	DQN	4	3000	180.0	8.4	1.16	1.16	0.5	4.0	8.0	Q2



www.ti.com 30-Apr-2024



*All dimensions are nominal

7 till dillitorioriorio di o mominidi							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS7A20L10PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A20L12PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A20L18PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A20L28PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0
TPS7A20L33PDQNR	X2SON	DQN	4	3000	210.0	185.0	35.0

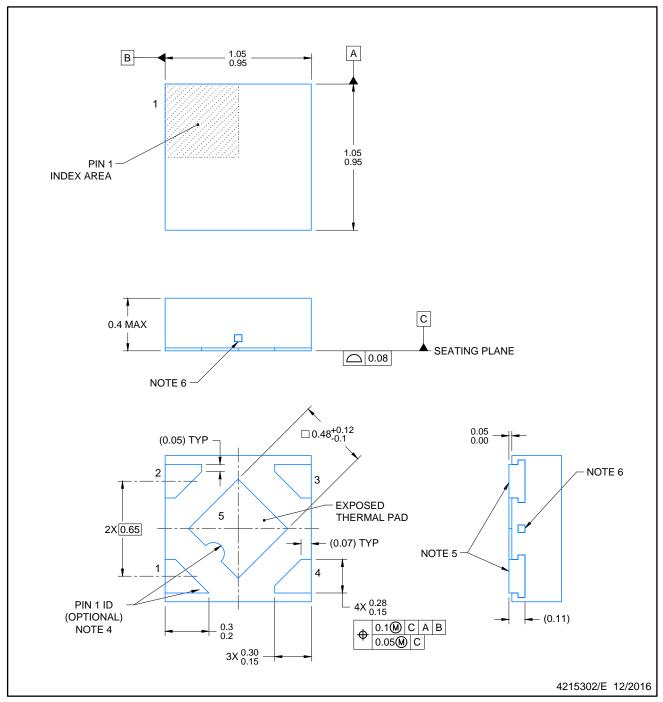


Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4210367/F



PLASTIC SMALL OUTLINE - NO LEAD

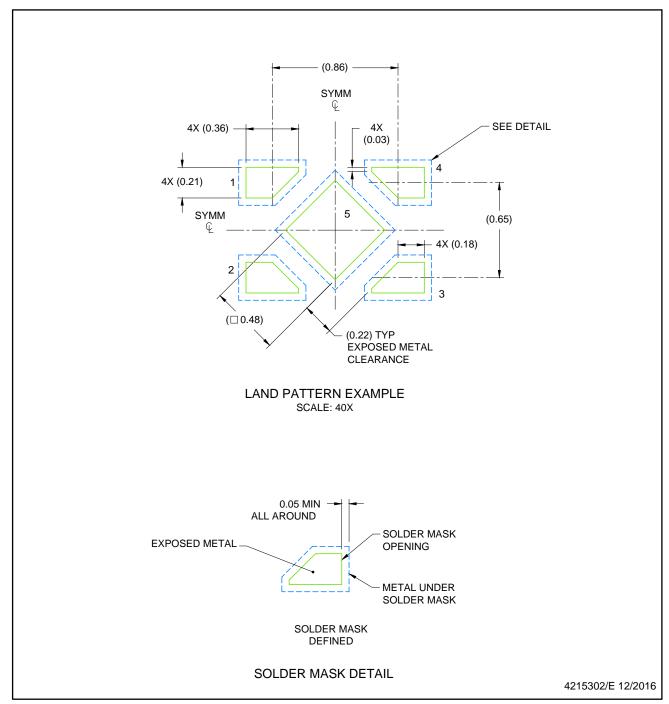


NOTES:

- All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.
- 4. Features may not exist. Recommend use of pin 1 marking on top of package for orientation purposes.
- 5. Shape of exposed side leads may differ.
- 6. Number and location of exposed tie bars may vary.



PLASTIC SMALL OUTLINE - NO LEAD

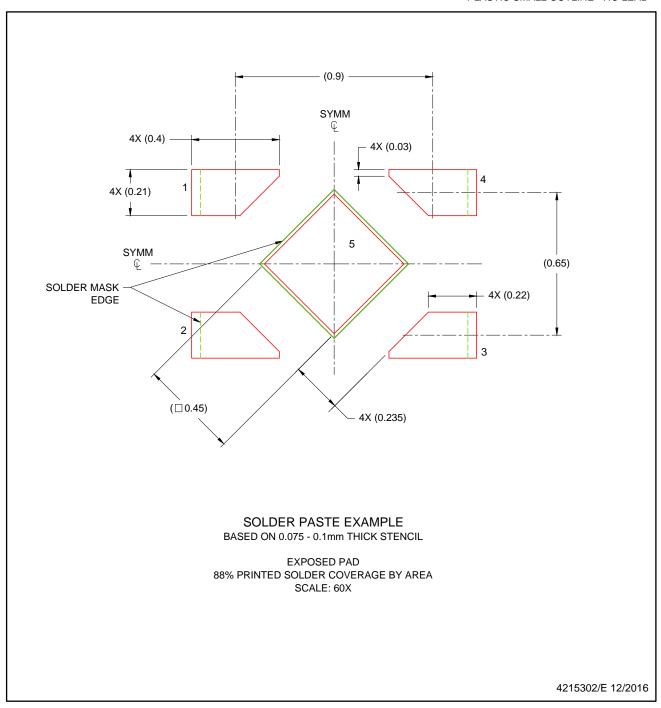


NOTES: (continued)

- 7. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
- 8. If any vias are implemented, it is recommended that vias under paste be filled, plugged or tented.



PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate
design recommendations.



IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you fully indemnify TI and its representatives against any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale, TI's General Quality Guidelines, or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products. Unless TI explicitly designates a product as custom or customer-specified, TI products are standard, catalog, general purpose devices.

TI objects to and rejects any additional or different terms you may propose.

Copyright © 2025, Texas Instruments Incorporated

Last updated 10/2025